## NSN 5961-00-553-8972

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-553-8972 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **End Application:** General purpose electronic test equipment gpete; spruance class dd (963); oliver perry class ffg; arleigh burke class ddg; tarawa class lha; whidbey island class lsd; ticobderoga class cg (47); strategic sealift conversion ships class; wasp class lhd; nimitz class cvn **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapon system essential **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: